

**Vishay Siliconix** 

## Low Power, High Voltage SPST Analog Switches

#### DESCRIPTION

The DG467 and DG468 are dual supply single-pole/singlethrow (SPST) switches. On resistance is 10  $\Omega$  max. and flatness is 2  $\Omega$  max. over the specified analog signal range. These analog switches were designed to provide high speed, low error switching of precision analog signals. The primary application areas are in the routing and switching in telecommunications and test equipment. Combining low power, low leakages, low on-resistance and small physical size, the DG467/468 are also ideally suited for portable and battery powered industrial and military equipment.

The DG467 has one normally closed switch, while the DG468 switch is normally open. They operate either from a single + 7 V to 36 V supply or from dual ± 4.5 V to ± 20 V supplies. They are offered in the very popular, small TSOP6 package.

#### **FEATURES**

- ± 15 V Analog Signal Range
- On-Resistance  $R_{DS(on)}$ : 10  $\Omega$  max.
- Fast Switching Action T<sub>ON</sub>: 100 ns
- V<sub>I</sub> Logic Supply Not Required
- **TTL CMOS Input Compatible**
- Rail To Rail Signal Handling
- **Dual Or Single Supply Operation**
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

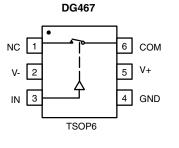
#### **BENEFITS**

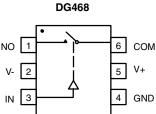
- Wide Dynamic Range
- Low Signal Errors and Distortion
- Break-Befor-Make Switching Action
- Simple Interfacing
- **Reduced Board Space**
- Improved Reliability

#### APPLICATIONS

- **Precision Test Equipment**
- Precision Instrumentaion
- **Communications Systems**
- PBX, PABX Systems
- Audio Equipment
- **Redundant Systems**
- PC Multimedia Boards
- Hard Disc Drivers

#### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TSOP6

TRUTH TABLE						
Logic	DG467	DG468				
0	ON	OFF				
1	OFF	ON				

Logic "0"  $\leq$  0.8 V Logic "1"  $\ge$  2.4 V

**Device Marking:** DG467DV = G7xxxDG468DV = G8xxx

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COMPLIANT HALOGEN

FREE

# DG467, DG468

## Vishay Siliconix



ORDERING INFORMATION								
Temp Range Package Part Number								
DG467/DG468								
- 40 °C to 85 °C	6-Pin TSOP	DG467DV-T1-E3						
- 40 0 10 85 0	0-FIII 130F	DG468DV-T1-E3						

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ , unless otherwise noted)					
Parameter Referenced To V-		Symbol	Limit	Unit	
V+			44		
GND			25	V	
Digital Inputs <sup>a</sup> , V <sub>NO/NC</sub> , V <sub>COM</sub>			(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first		
Current, (Any Terminal) Continuous			30	mA	
Current (NO or NC or COM) Pulsed at 1 ms, 10 % duty cycle			100	IIIA	
Storage Temperature			- 65 to 150	°C	
Power Dissipation (Package) <sup>b</sup>	6-Pin TSOP <sup>c</sup>		570	mW	

Notes:

a. Signals on NO, NC, COM, or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC Board.

c. Derate 7 mW/°C above 70 °C.



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SPECIFICATIONS <sup>a</sup> (V	± = ± 15 V)						
		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V				Suffix C to 85 °C	
Parameter	Symbol	$V_{IN} = 2.4 \text{ V}, 0.8 \text{ V}^{\text{f}}$	Temp. <sup>b</sup>	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max. <sup>d</sup>	Unit
Analog Switch							
Analog Signal Range <sup>eron</sup>	V <sub>ANALOG</sub>		Full	- 15		15	V
Drain-Source On-Resistance	R <sub>ON</sub>	I <sub>NO/NC</sub> = 10 mA, V <sub>COM</sub> = 10 V V+ = 13.5 V, V- = - 13.5 V	Room Full		7	9 10	Ω
On-Resistance Flatness	R <sub>ON</sub> Flatness	I <sub>NO/NC</sub> = 10 mA, V <sub>COM</sub> = ± 5 V, 0 V V+ = 13.5 V, V- = - 13.5 V	Room Full		0.7	1 2	52
Switch Off Leakage Current	I <sub>NO/NC(off)</sub>	V+ = 16.5, V- = - 16.5 V V <sub>COM</sub> = ± 15.5 V	Room Full	- 1 - 10	- 0.1	1 10	
	I <sub>COM(off)</sub>	$V_{NO/NC} = -/+ 15.5 V$	Room Full	- 1 - 10	- 0.1	1 10	nA
Channel On Leakage Current	I <sub>COM(on)</sub>	V+ = 16.5 V, V- = - 16.5 V <sub>COM</sub> = V <sub>NO/NC</sub> = ± 15.5 V	Room Full	- 1 - 10	- 0.1	1 10	
Digital Control							
Input, High Voltage	V <sub>INH</sub>		Full	2.4			v
Input, Low Voltage	V <sub>INL</sub>		Full			0.8	v
Input Capacitance <sup>e</sup>	C <sub>IN</sub>		Room		5		pF
Input Current	I <sub>IN</sub>	$V_{IN} = 0 \text{ or } 5 \text{ V}$		- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room Full		100	140 160	ns
Turn-Off Time	t <sub>OFF</sub>	$V_{NO/NC} = \pm 10 V$	Room Full		50	80 100	110
Charge Injection <sup>e</sup>	Q	$C_L$ = 1 nF, $V_{gen}$ = 0 V, $R_{gen}$ = 0 $\Omega$	Room		21		рС
Off-Isolation <sup>e</sup>	OIRR	$C_L$ = 5 pF, $R_L$ = 50 Ω, f = 1 MHz	Room		- 61		dB
Source Off Capacitance <sup>e</sup>	C <sub>S(off)</sub>	f = 1 MHz	Room		30		
Drain Off Capacitance <sup>e</sup>	C <sub>D(off)</sub>	1 – 1 10112	Room		15		pF
Channel On Capacitance <sup>e</sup>	C <sub>D(on)</sub>	f = 1 MHz	Room		76		
Power Supplies							
Positive Supply Current	l+	V+ = 16.5 V, V- = - 16.5 V	Room Full		5	15 20	μA
Negative Supply Current	I-	V <sub>IN</sub> = 0 or 5 V	Room Full	- 1 - 10	- 0.02		- <sup>20</sup>

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SPECIFICATIONS <sup>a</sup> (V+ = 12 V)								
		Test Conditions Unless Otherwise Specified		<b>D Suffix</b> - 40 °C to 85				
Parameter	Symbol	V+ = 12 V, V- = 0 V V <sub>IN</sub> = 2.4 V, 0.8 V <sup>f</sup>	Temp. <sup>b</sup>	Min. <sup>d</sup>	Typ. <sup>c</sup>	Max. <sup>d</sup>	Unit	
Analog Switch								
Analog Signal Range <sup>e</sup>	V <sub>ANALOG</sub>		Full	0		12	V	
Drain-Source On-Resistance	R <sub>ON</sub>	I <sub>NO/NC</sub> = -10 mA, V <sub>COM</sub> = 8 V V+ = 10.8 V	Room Full		12	16 20	Ω	
On-Resistance Flatness	R <sub>ON</sub> Flatness	$I_{NO/NC} = 10 \text{ mA}, V_{COM} = 2, 6, 8 \text{ V}$ V+ = 10.8 V	Room Full		1.5	3 4	Ω	
Dynamic Characteristics					•	•	•	
Turn-On Time	t <sub>ON</sub>	V <sub>NO, NC</sub> = ± 10 V, R <sub>L</sub> = 300 Ω, C <sub>L</sub> = 35 pF	Room Full		130	160 200	nS	
Turn-Off Time	t <sub>OFF</sub>	$V_{NO, NC} = \pm 10^{\circ} v, H_{L} = 300^{\circ} s2, O_{L} = 35^{\circ} pr$	Room Full		50	80 100	115	
Charge Injection <sup>e</sup>	Q	$C_L = 1 \text{ nF}, V_{gen} = 0 \text{ V}, \text{ R}_{gen} = 0 \Omega$	Room		8		рС	
Power Supplies								
Positive Supply Current	l+	V+ = 13.2 V, V <sub>IN</sub> = 0 V, 5 V	Room Full		3	7 10	μΑ	

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

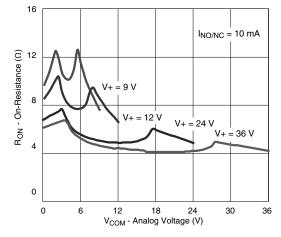
f.  $V_{IN}$  = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

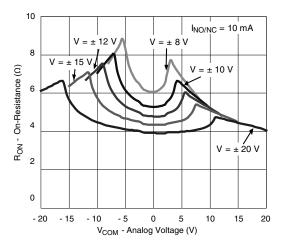


## DG467, DG468 Vishay Siliconix

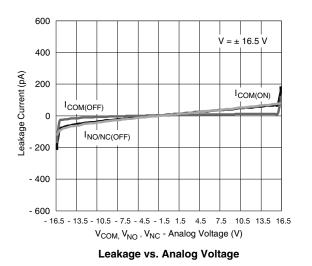
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)

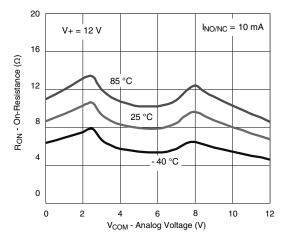


 $\mathbf{R}_{\text{ON}}$  vs.  $\mathbf{V}_{\text{COM}}$  and Single Supply Voltage

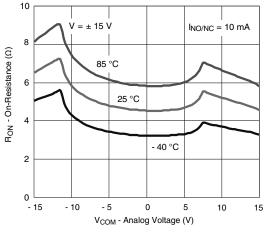


 $R_{ON} \mbox{ vs. } V_{COM}$  and Dual Supply Voltage

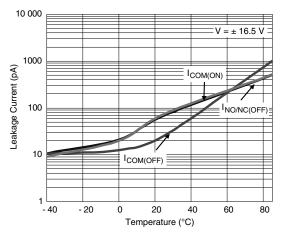




R<sub>ON</sub> vs. Analog Voltage and Temperature



R<sub>ON</sub> vs. Analog Voltage and Temperature



Leakage Current vs. Temperature

5

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# DG467, DG468

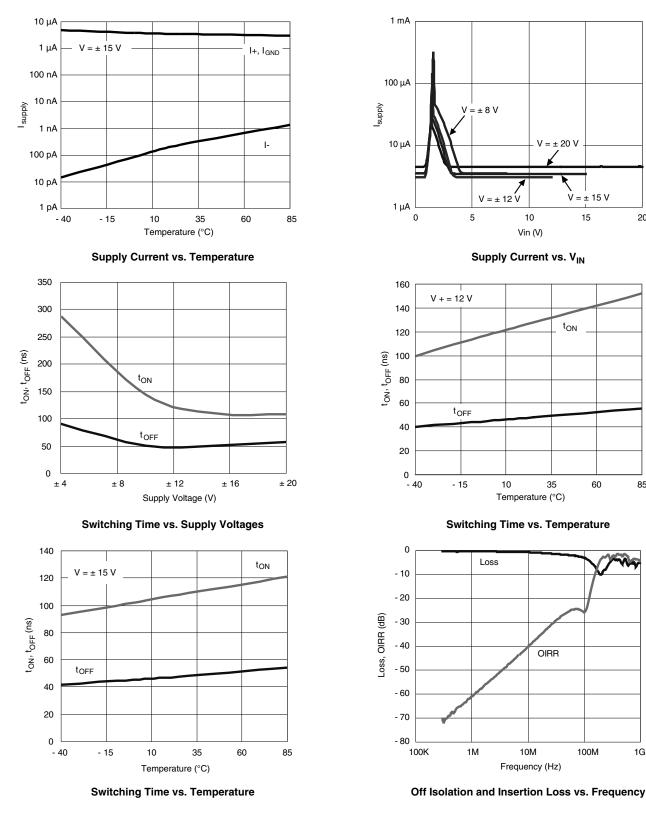


20

85

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### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)





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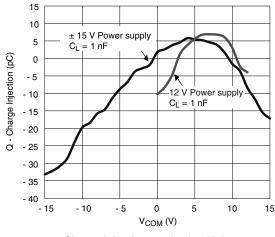
1G

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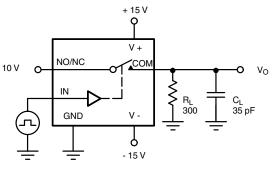
### **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



Charge Injection vs. Analog Voltage

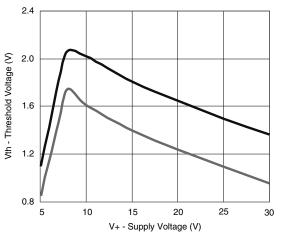
### **TEST CIRCUITS**

 $V_{O}$  is the steady state output with the switch on.

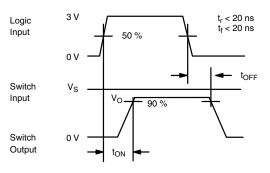


 $C_L$  (includes fixture and stray capacitance)

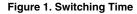
$$V_{O} = V_{S}$$
  $\frac{R_{L}}{R_{L} + r_{ON}}$ 

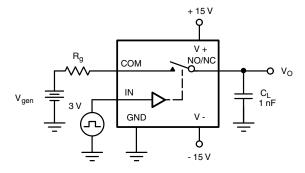


Input Switching Threshold vs. Supply Voltage



Note: Logic input waveform is inverted for switches that have the opposite logic sense.





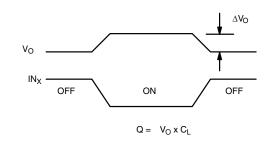


Figure 2. Charge Injection

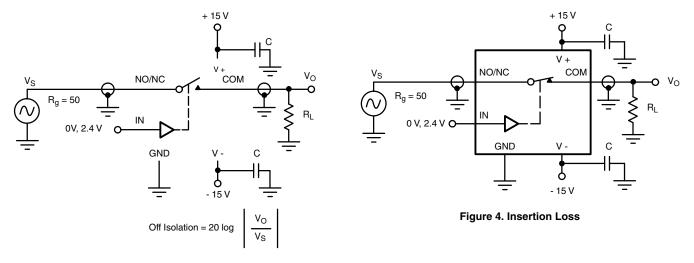
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## DG467, DG468

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### **TEST CIRCUITS**

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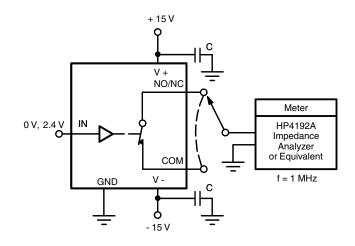


Figure 5. Source/Drain Capacitances

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For technical questions, contact: <a href="mailto:analogswitchtechsuoort@vishay.com">analogswitchtechsuoort@vishay.com</a>

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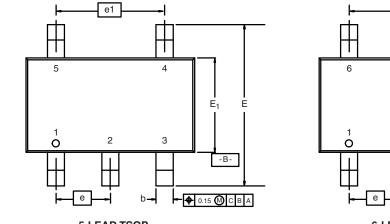




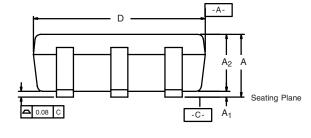
Package Information

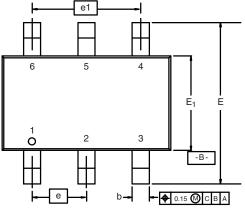
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TSOP: 5/6-LEAD JEDEC Part Number: MO-193C

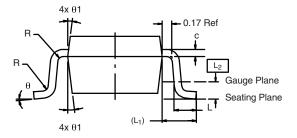








6-LEAD TSOP



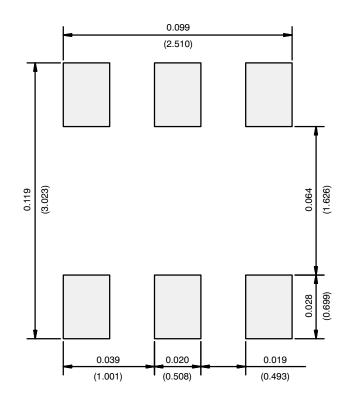
	MIL	LIMETE	RS	INCHES				
Dim	Min	Nom	Max	Min	Nom	Max		
Α	0.91	-	1.10	0.036	-	0.043		
<b>A</b> <sub>1</sub>	0.01	-	0.10	0.0004	-	0.004		
A <sub>2</sub>	0.90	-	1.00	0.035	0.038	0.039		
b	0.30	0.32	0.45	0.012	0.013	0.018		
С	0.10	0.15	0.20	0.004	0.006	0.008		
D	2.95	3.05	3.10	0.116	0.120	0.122		
Е	2.70	2.85	2.98	0.106	0.112	0.117		
E <sub>1</sub>	1.55	1.65	1.70	0.061	0.065	0.067		
е		0.95 BSC		0.0374 BSC				
<b>e</b> <sub>1</sub>	1.80	1.90	2.00	0.071 0.075		0.079		
L	0.32	-	0.50	0.012	-	0.020		
L <sub>1</sub>	0.60 Ref			0.024 Ref				
L <sub>2</sub>	0.25 BSC			0.010 BSC				
R	0.10	-	-	0.004	-	-		
θ	0°	4°	8°	0°	4°	8°		
$\theta_1$	7° Nom 7° Nom							
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540								

# **Application Note 826**

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**RECOMMENDED MINIMUM PADS FOR TSOP-6** 



Recommended Minimum Pads Dimensions in Inches/(mm)

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